

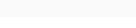
MMBT4401WT1G

Data Sheet

BIPOLAR TRANSISTOR, NPN, 40V, Transistor Polarity:NPN, Collector Emitter Voltage V(br)ceo:40V, Transition Frequency ft:250MHz, Power Dissipation Pd:150mW, DC Collector Current:600mA, DC Current Gain hFE:100hFE

Manufacturers	ON Semiconductor, LLC	
Package/Case	SC-70-3	
Product Type	Transistors	
RoHS	Rohs	Images are for reference only
Lifecycle		

Please submit RFQ for MMBT4401WT1G or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

The NPN Bipolar Transistor is designed for general purpose amplifier applications. It is housed in the SOT-323/SC-70 package, which is designed for low power surface mount applications.

Features

Moisture Sensitivity Level: 1

ESD Rating: Human Body Model - 4 kVMachine Model - 400 V

Pb-Free Package is Available

Related Products



MMPQ6700

ON Semiconductor, LLC SOIC-16



ON Semiconductor, LLC SC-70

MMBT2222AWT3G



SOP-16



MMPQ2907A

ON Semiconductor, LLC

MMPQ3906

ON Semiconductor, LLC SOIC-16



Ovaga Technologies Limited

RFO

Application

ONSEMI



MMPQ3904

ON Semiconductor, LLC SOIC-16



MMBT3906TT1G ON Semiconductor, LLC

NSVMMBT3906TT1G

ON Semiconductor, LLC SC-75-3

MMBT2222ATT1G

SC-75-3

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